

Preview

DC-9GHz, 11dBm Wideband General Purpose Amplifier

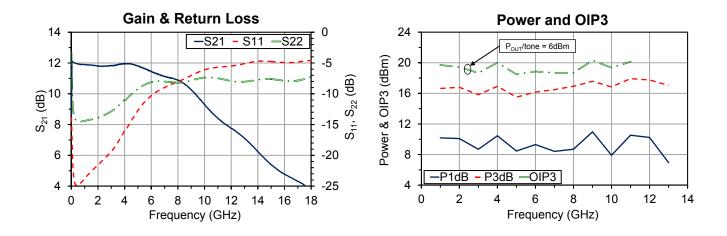
Features

- >16dBm P_{3dB} to 9GHz
- >10dB gain to 9GHz
- Input and output matched to 50Ω
- 100% DC and RF tested
- 3x3 DFN-6 plastic overmold package

Applications

- Instrumentation
- Electronic warfare
- Microwave communications
- Radar





Typical Performance (CW, Typical Device, Evaluation Board): $T_A = 25^{\circ}C$, $V_{DD} = 4V$

Parameter	DC - 9GHz	Units
Small Signal Gain	11	dB
Output Power, P _{1dB}	9	dBm
Output Power P _{3dB}	17	dBm
Output IP3	TBD	dBm
I _{DD}	24	mA



Table 1: Absolute Maximum Ratings, Not Simultaneous

Parameter	Rating	Units
Drain Voltage (V _{DD})	+4.5	V
Input Power (P _{IN})	TBD (6 est)	dBm
Channel Temperature (T _c)	150 ¹	°C
Operating Ambient Temperature (T _A)	-55 to +85	°C
Storage Temperature	-65 to +150	°C
Thermal Resistance, Channel to Die Backside (R_{TH})	TBD	°C/W



Caution, ESD Sensitive Device

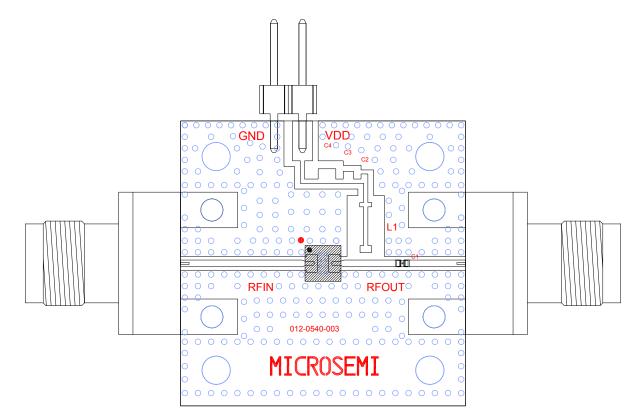
¹ MTTF > 10⁸ hours at $T_c = 150^{\circ}C$

Table 2: Specifications (CW, 100% Test): $T_A = 25^{\circ}C$, $V_{DD} = 4V$

Parameter	Frequency	Min	Тур	Мах	Units
I _{DD}	-	TBD	24	TBD	mA
Small Signal Gain	9GHz	TBD	TBD	-	dB
Output Power, P _{1dB}	9GHz	TBD	TBD	-	dBm

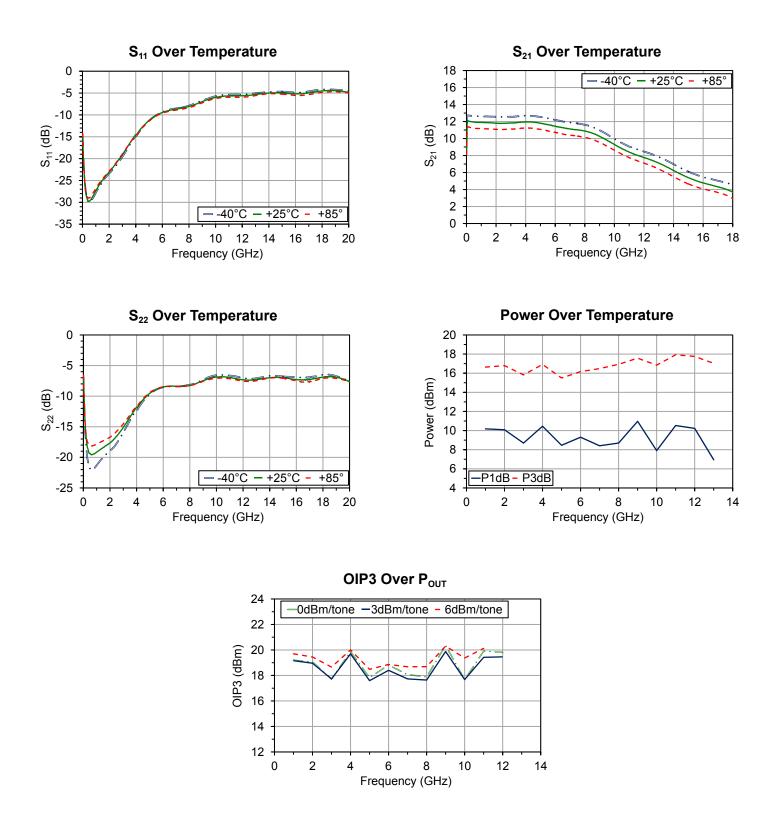
Evalutation Board

With SMK 2.92mm Connectors





Typical Performance $V_{DD} = 4V, I_{DD} = 24mA, T_A = 25^{\circ}C$, in evaluation board, unless otherwise noted



Preview, Rev -Subject to Change Without Notice



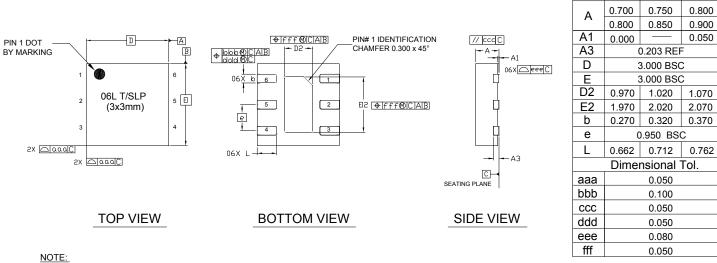
Preview

Dimensional Ref.

Max.

REF. Min. Nom

Microsemi QA Package Outline



DIMENSIONS ARE IN MM

Table 3: Pinout

Pad #	Description
1,3,4,6	Ground
2	RF _{IN} , Pad is DC Coupled
5	RF _{OUT} , Pad is DC Coupled
Exposed Pad	Ground, thermal path



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